TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED TYPE

2 S C 5 3 5 8

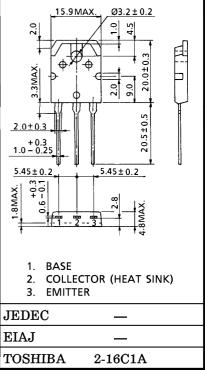
POWER AMPLIFIER APPLICATIONS

- Complementary to 2SA1986
- Recommend for 80W High Fidelity Audio Frequency Amplifier Output Stage.

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	v_{CBO}	230	V
Collector-Emitter Voltage	v_{CEO}	230	V
Emitter-Base Voltage	$v_{ m EBO}$	5	V
Collector Current	IC	15	A
Base Current	$I_{\mathbf{B}}$	1.5	A
Collector Power Dissipation (Tc=25°C)	PC	150	W
Junction Temperature	$T_{\rm j}$	150	°C
Storage Temperature Range	$ m T_{stg}$	-55~150	°C

Unit in mm



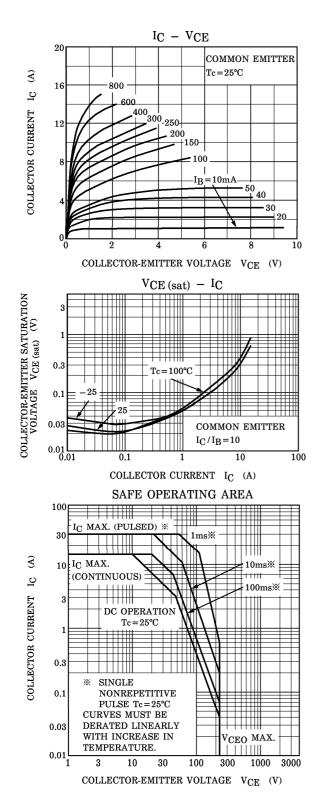
Weight: 4.7g (Typ.)

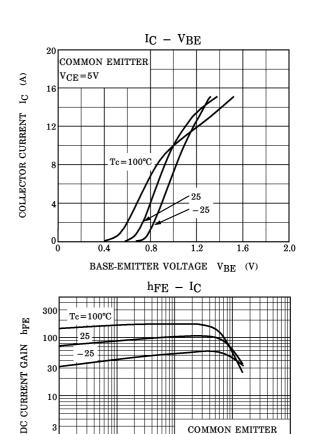
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB} = 230V, I_{E} = 0$	_	_	5.0	μ A
Emitter Cut-off Current	$I_{ m EBO}$	$V_{EB} = 5V, I_C = 0$	_	_	5.0	μ A
Collector-Emitter Breakdown Voltage	V (BR) CEO	$I_{\rm C} = 50 {\rm mA}, \ I_{\rm B} = 0$	230	_	_	V
DC Current Gain	hFE (1) (Note)	$V_{\rm CE}$ =5V, $I_{\rm C}$ =1A	55	_	160	_
	h _{FE} (2)	$V_{CE}=5V, I_{C}=7A$	35	87		
Collector-Emitter Saturation Voltage	V _{CE (sat)}	$I_{\rm C} = 8A, I_{\rm B} = 0.8A$	_	0.4	3.0	V
Base-Emitter Voltage	$ m V_{BE}$	$V_{CE}=5V, I_{C}=7A$	_	1.0	1.5	V
Transition Frequency	$ m f_{T}$	$V_{CE}=5V$, $I_{C}=1A$	_	30	_	MHz
Collector Output Capacitance	C_{ob}	$V_{CB} = 10V, I_{E} = 0, f = 1MHz$	_	200	_	pF

(Note) $h_{FE(1)}$ Classification $R:55\sim110$, $O:80\sim160$

2001-05-24





0.01

0.1

 $V_{CE} = 5V$

COLLECTOR CURRENT I_C (A)

100

2 2001-05-24

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